

TOSHIBA Field Effect Transistor Silicon P/N Channel MOS Type(π-MOSVI)

SSM6L16FE

High Speed Switching Applications

Analog Switch Applications

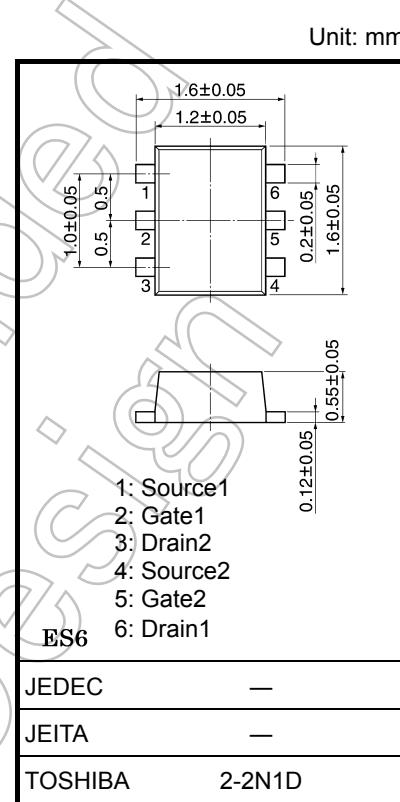
- Small package
- Low onresistance Q1: $R_{DS(ON)} = 4 \Omega$ (max) (@ $V_{GS} = 2.5$ V)
Q2: $R_{DS(ON)} = 12 \Omega$ (max) (@ $V_{GS} = -2.5$ V)

Q1 Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Drain-Source voltage	V_{DSS}	20	V
Gate-Source voltage	V_{GSS}	± 10	V
Drain current	DC	I_D	100
	Pulse	I_{DP}	200
			mA

Q2 Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Drain-Source voltage	V_{DSS}	-20	V
Gate-Source voltage	V_{GSS}	± 10	V
Drain current	DC	I_D	-100
	Pulse	I_{DP}	-200
			mA



Weight: 3 mg (typ.)

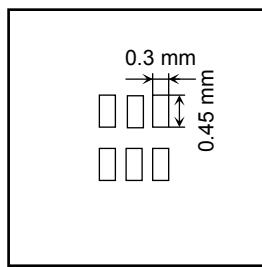
Absolute Maximum Ratings (Q1, Q2 Common) ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Power dissipation	P_D (Note 1)	150	mW
Channel temperature	T_{ch}	150	°C
Storage temperature range	T_{stg}	-55 to 150	°C

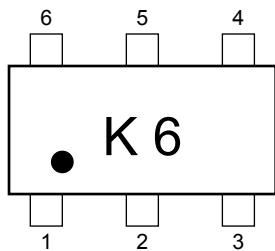
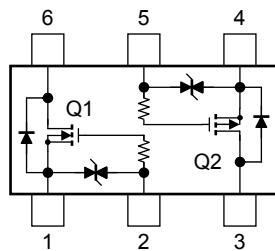
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Total rating, mounted on FR4 board
(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 0.135 mm² × 6)



Start of commercial production
2002-03

Marking**Equivalent Circuit (top view)****Handling Precaution**

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

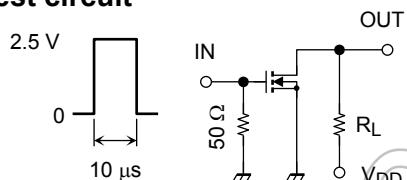
Q1 Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT
Gate leakage current	I_{GSS}	$V_{GS} = \pm 10\text{ V}, V_{DS} = 0$	—	—	± 1	μA
Drain-Source breakdown voltage	$V_{(\text{BR})\text{ DSS}}$	$I_D = 0.1\text{ mA}, V_{GS} = 0$	20	—	—	V
Drain cut-off current	I_{DSS}	$V_{DS} = 20\text{ V}, V_{GS} = 0$	—	—	1	μA
Gate threshold voltage	V_{th}	$V_{DS} = 3\text{ V}, I_D = 0.1\text{ mA}$	0.6	—	1.1	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3\text{ V}, I_D = 10\text{ mA}$ (Note2)	40	—	—	mS
Drain-Source on-resistance	$R_{DS(\text{ON})}$	$I_D = 10\text{ mA}, V_{GS} = 4\text{ V}$ (Note2)	—	1.5	3.0	Ω
		$I_D = 10\text{ mA}, V_{GS} = 2.5\text{ V}$ (Note2)	—	2.2	4.0	
		$I_D = 1\text{ mA}, V_{GS} = 1.5\text{ V}$ (Note2)	—	5.2	15	
Input capacitance	C_{iss}	$V_{DS} = 3\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	9.3	—	pF
Reverse transfer capacitance	C_{rss}		—	4.5	—	pF
Output capacitance	C_{oss}		—	9.8	—	pF
Switching time	Turn-on time	t_{on}	$V_{DD} = 3\text{ V}, I_D = 10\text{ mA}, V_{GS} = 0\text{ to }2.5\text{ V}$	70	—	ns
	Turn-off time	t_{off}		125	—	

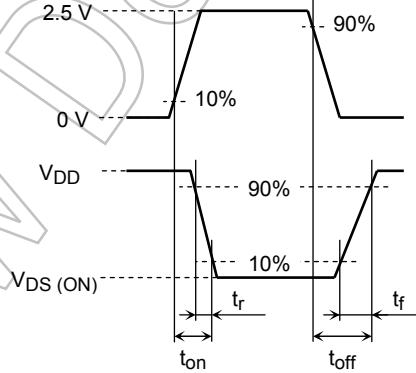
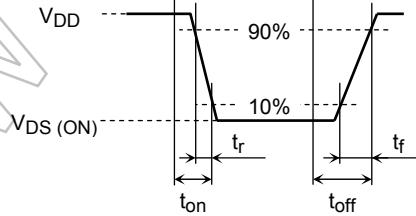
Note2: Pulse test

Switching Time Test Circuit

(a) Test circuit



$V_{DD} = 3\text{ V}$
 Duty $\leq 1\%$
 $V_{IN}: t_r, t_f < 5\text{ ns}$
 $(Z_{out} = 50\Omega)$
 Common Source
 $T_a = 25^\circ\text{C}$

(b) V_{IN} (c) V_{OUT} 

Precaution

V_{th} can be expressed as the voltage between the gate and source when the low operating current value is $I_D = 0.1\text{ mA}$ for this product. For normal switching operation, V_{GS} (on) requires a higher voltage than V_{th} and V_{GS} (off) requires a lower voltage than V_{th} . (The relationship can be established as follows: V_{GS} (off) $< V_{th} < V_{GS}$ (on).)

Be sure to take this into consideration when using the device.

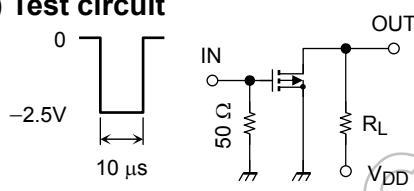
Q2 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT
Gate leakage current	I _{GSS}	V _{GS} = ±10 V, V _{DS} = 0	—	—	±1	μA
Drain-Source breakdown voltage	V _{(BR) DSS}	I _D = -0.1 mA, V _{GS} = 0	-20	—	—	V
Drain cut-off current	I _{DSS}	V _{DS} = -20 V, V _{GS} = 0	—	—	-1	μA
Gate threshold voltage	V _{th}	V _{DS} = -3 V, I _D = -0.1 mA	-0.6	—	-1.1	V
Forward transfer admittance	Y _{fs}	V _{DS} = -3 V, I _D = -10 mA (Note3)	25	—	—	mA
Drain-Source on-resistance	R _{DS (ON)}	I _D = -10 mA, V _{GS} = -4 V (Note3)	—	6	8	Ω
		I _D = -10 mA, V _{GS} = -2.5 V (Note3)	—	8	12	
		I _D = -1 mA, V _{GS} = -1.5 V (Note3)	—	18	45	
Input capacitance	C _{iss}	V _{DS} = -3 V, V _{GS} = 0, f = 1 MHz	—	11	—	pF
Reverse transfer capacitance	C _{rss}		—	3.7	—	pF
Output capacitance	C _{oss}		—	10	—	pF
Switching time	Turn-on time	t _{on}	V _{DD} = -3 V, I _D = -10 mA, V _{GS} = 0 to -2.5 V	130	—	ns
	Turn-off time	t _{off}		190	—	

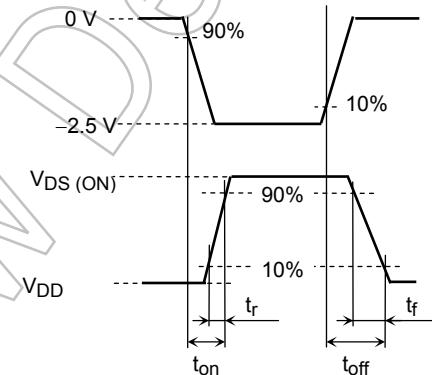
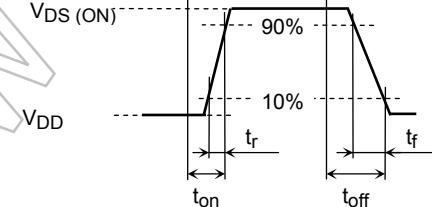
Note3: Pulse test

Switching Time Test Circuit

(a) Test circuit



V_{DD} = -3 V
 Duty ≤ 1%
 V_{IN}: t_r, t_f < 5 ns
 (Z_{out} = 50 Ω)
 Common Source
 Ta = 25°C

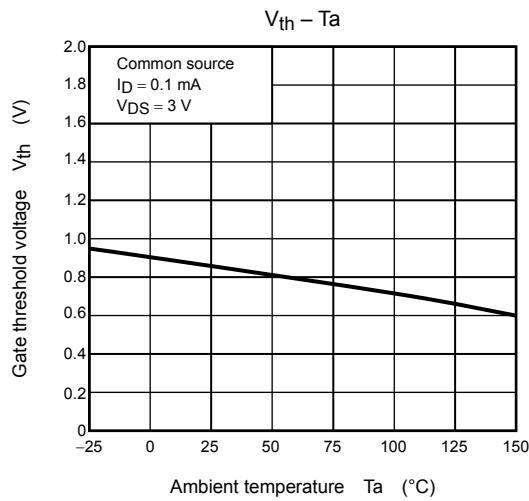
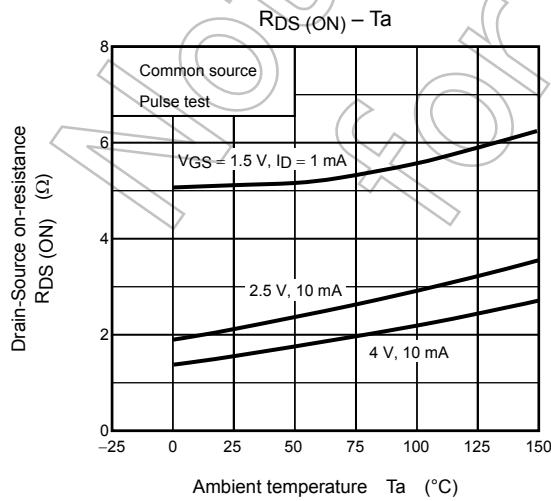
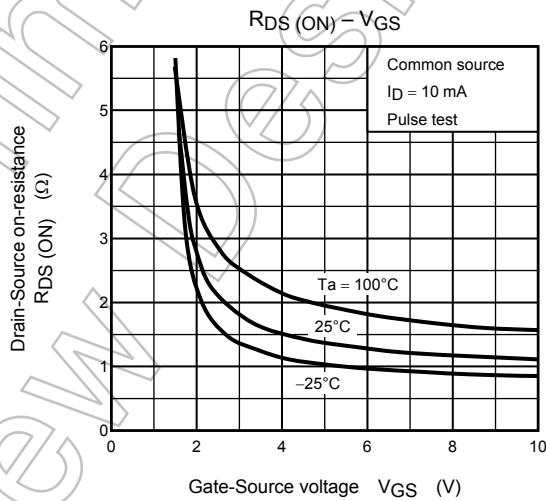
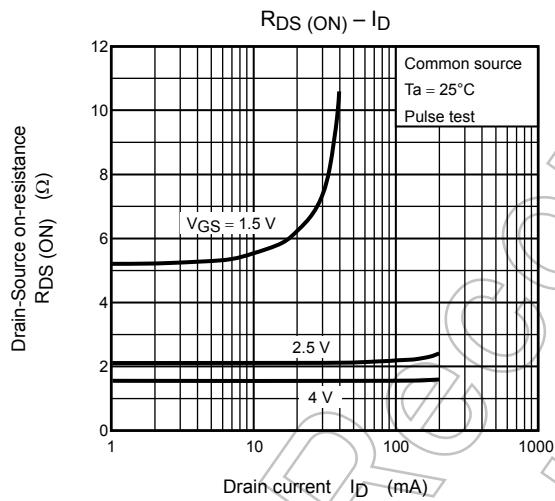
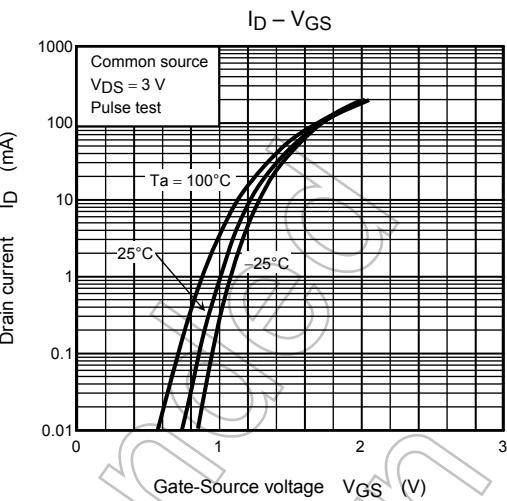
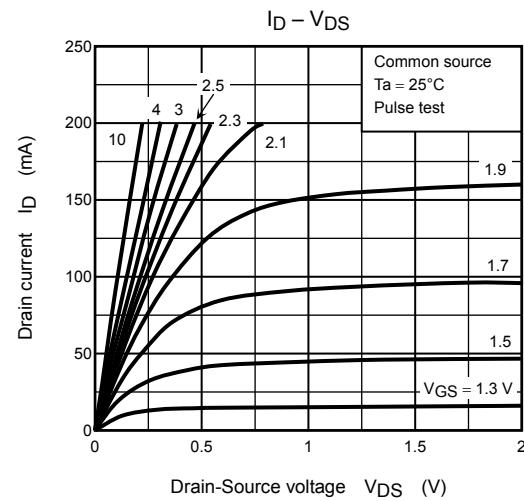
(b) V_{IN}(c) V_{OUT}

Precaution

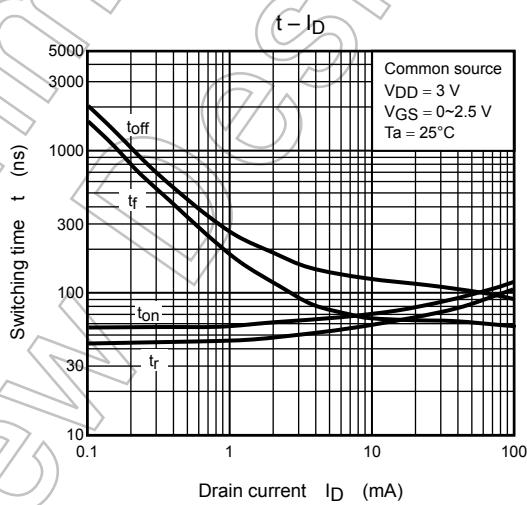
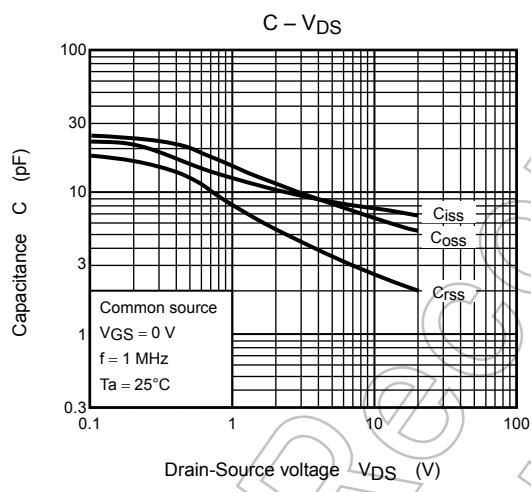
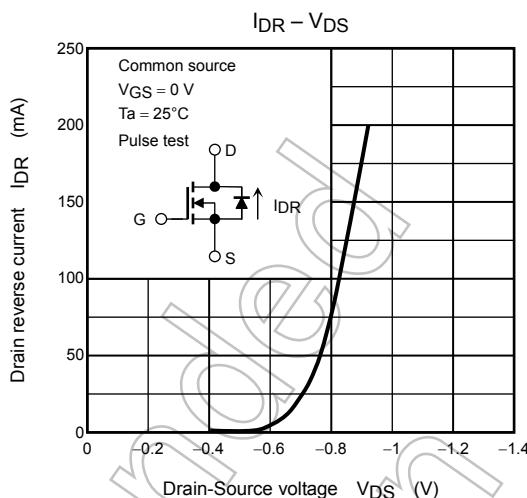
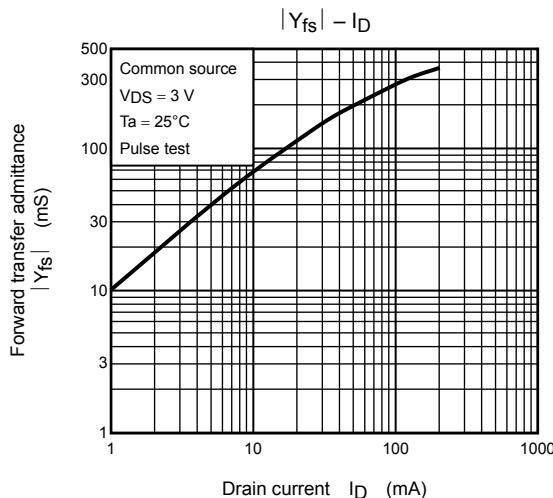
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Be sure to take this into consideration when using the device.

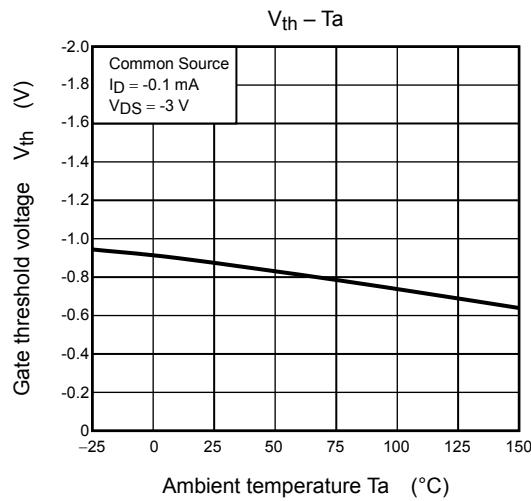
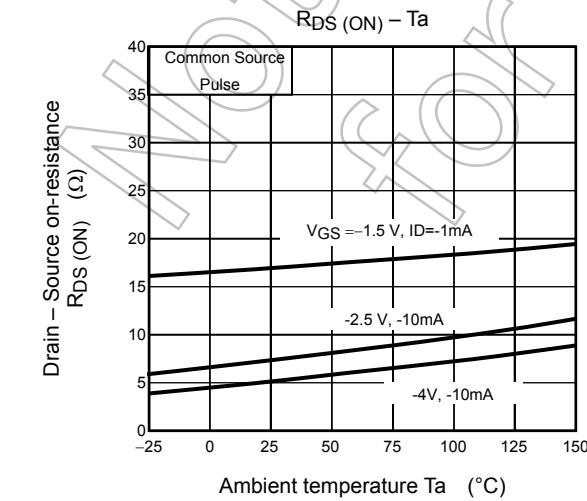
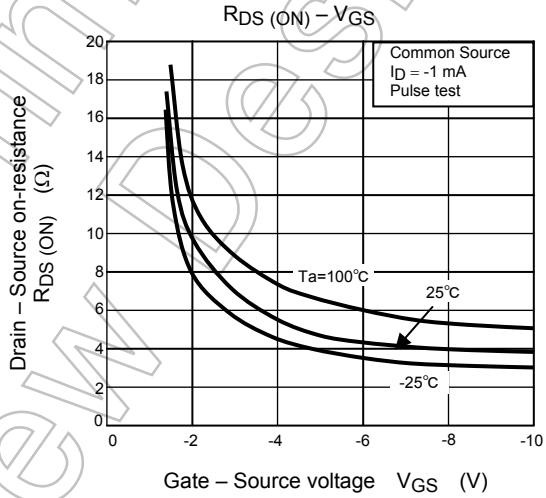
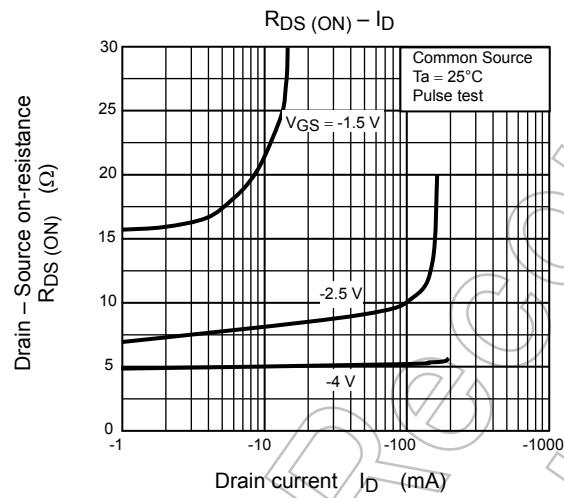
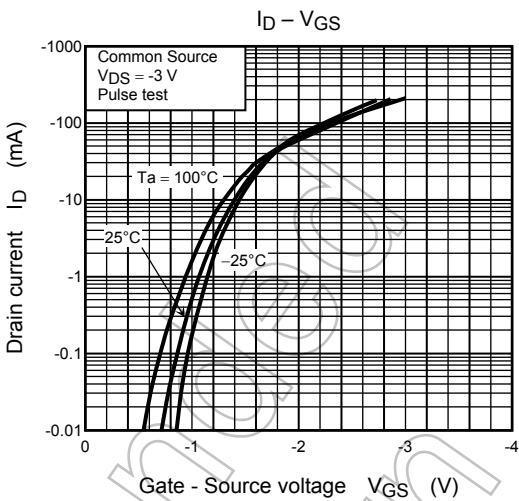
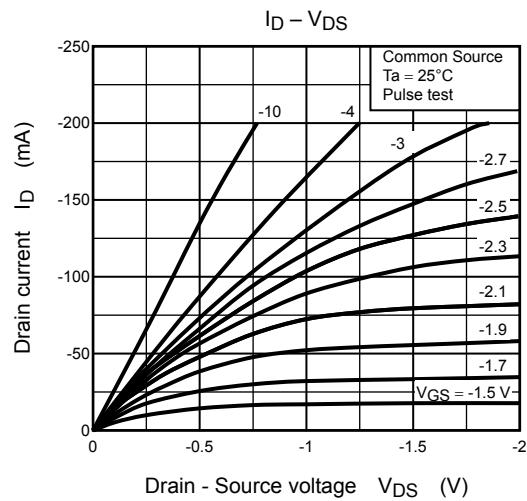
Q1 (N-ch MOSFET)



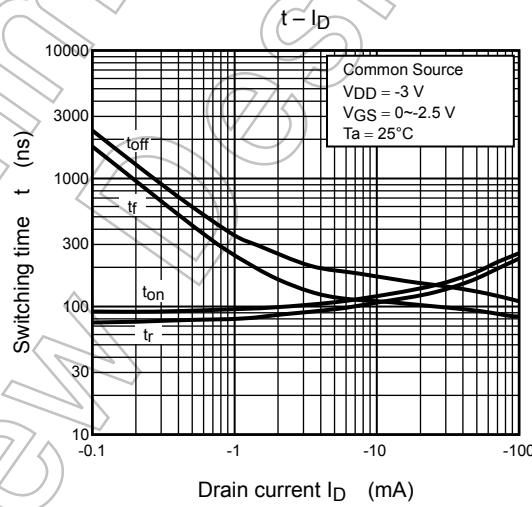
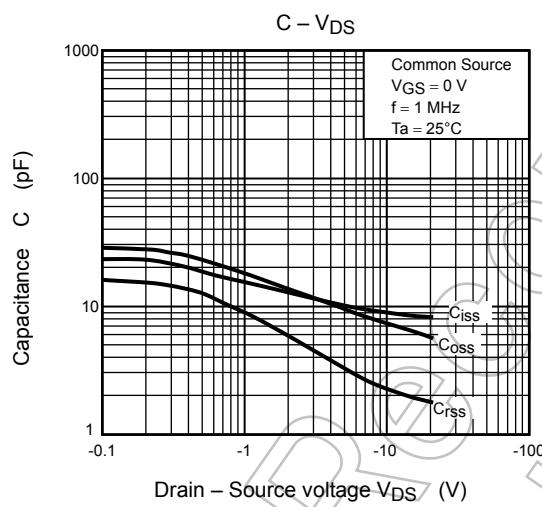
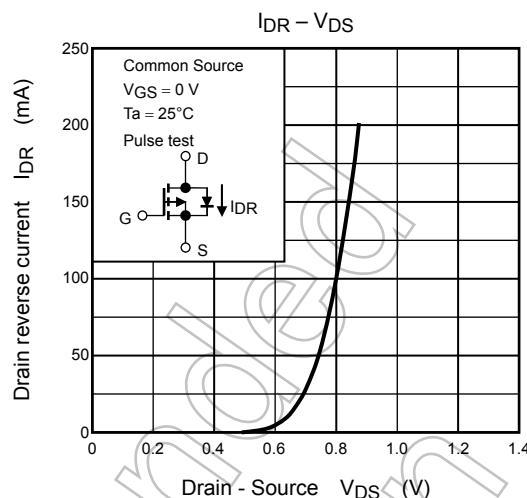
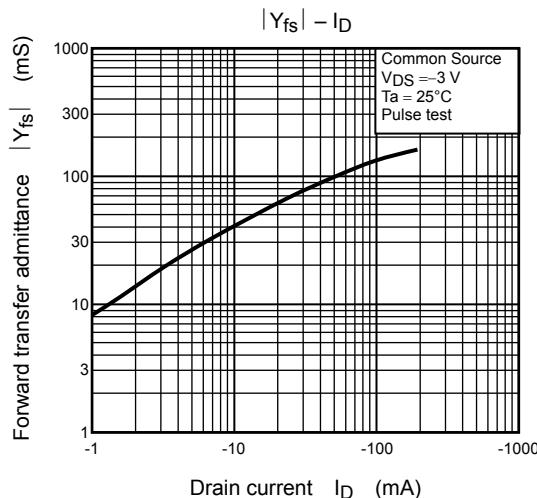
Q1 (N-ch MOSFET)



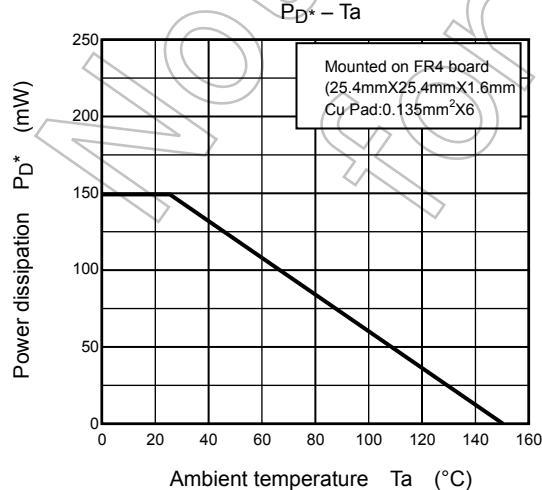
Q2 (P-ch MOSFET)



Q2 (P-ch MOSFET)



Common Characteristics



*.Total rating

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